# VEMD6010X01

**Vishay Semiconductors** 



#### DESCRIPTION

VEMD6010X01 is a high speed and high sensitive PIN photodiode. It is a small surface mount device (SMD) including the chip with a 0.85 mm<sup>2</sup> sensitive area detecting visible and near infrared radiation.

### Silicon PIN Photodiode

### FEATURES

- · Package type: surface mount
- Package form: 1206
- Dimensions (L x W x H in mm): 4 x 2 x 1.05
- Radiant sensitive area (in mm<sup>2</sup>): 0.85
- · High photo sensitivity
- High radiant sensitivity
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity:  $\phi = \pm 60^{\circ}$
- Floor life: 72 h, MSL 4, acc. J-STD-020
- Lead (Pb)-free reflow soldering
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### **APPLICATIONS**

• High speed photo detector

| PRODUCT SUMMARY |                      |         |                       |  |
|-----------------|----------------------|---------|-----------------------|--|
| COMPONENT       | I <sub>ra</sub> (μΑ) | φ (deg) | λ <sub>0.1</sub> (nm) |  |
| VEMD6010X01     | 9.5                  | ± 60    | 430 to 1100           |  |

#### Note

• Test conditions see table "Basic Characteristics"

| ORDERING INFORMATION |               |                              |              |  |  |
|----------------------|---------------|------------------------------|--------------|--|--|
| ORDERING CODE        | PACKAGING     | REMARKS                      | PACKAGE FORM |  |  |
| VEMD6010X01          | Tape and reel | MOQ: 3000 pcs, 3000 pcs/reel | 1206         |  |  |

#### Note

· MOQ: minimum order quantity

| <b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_{amb} = 25 \text{ °C}$ , unless otherwise specified) |                                   |                   |             |      |  |
|---|-----------------------------------|-------------------|-------------|------|--|
| PARAMETER   | TEST CONDITION                    | SYMBOL            | VALUE       | UNIT |  |
| Reverse voltage   |                                   | V <sub>R</sub>    | 32          | V    |  |
| Power dissipation   | T <sub>amb</sub> ≤ 25 °C          | Pv                | 215         | mW   |  |
| Junction temperature  |                                   | Тj                | 110         | °C   |  |
| Operating temperature range   |                                   | T <sub>amb</sub>  | -40 to +110 | °C   |  |
| Storage temperature range   |                                   | T <sub>stg</sub>  | -40 to +110 | °C   |  |
| Soldering temperature   | Acc. reflow solder profile fig. 8 | T <sub>sd</sub>   | 260         | °C   |  |
| Thermal resistance junction/ambient   | Acc. J-STD-051                    | R <sub>thJA</sub> | 270         | K/W  |  |



e

ROHS COMPLIANT

HALOGEN

FREE GREEN

(5-2008)

# VEMD6010X01



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| <b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified) |  |                   |      |             |      |      |
|---|--|-------------------|------|-------------|------|------|
| PARAMETER   | TEST CONDITION   | SYMBOL            | MIN. | TYP.        | MAX. | UNIT |
| Forward voltage   | I <sub>F</sub> = 50 mA   | V <sub>F</sub>    |      | 1           |      | V    |
| Breakdown voltage   | I <sub>R</sub> = 100 μA, E = 0   | V <sub>(BR)</sub> | 32   |             |      | V    |
| Reverse dark current  | V <sub>R</sub> = 10 V, E = 0   | I <sub>ro</sub>   |      | 1           | 3    | nA   |
| Diode capacitance   | $V_{R} = 0 V, f = 1 MHz, E = 0$  | CD                |      | 12          |      | pF   |
|   | V <sub>R</sub> = 5 V, f = 1 MHz, E = 0                                       | CD                |      | 3.6         |      | pF   |
| Open circuit voltage  | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$                       | Vo                |      | 356         |      | mV   |
| Temperature coefficient of Vo   | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$                       | TK <sub>Vo</sub>  |      | -3.1        |      | mV/K |
| Short circuit current   | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$                       | l <sub>k</sub>    |      | 9           |      | μA   |
| Temperature coefficient of $I_k$  | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$                       | TK <sub>lk</sub>  |      | 0.1         |      | %/K  |
| Reverse light current   | $E_e = 1 \text{ mW/cm}^2$ , $\lambda = 950 \text{ nm}$ , $V_R = 5 \text{ V}$ | I <sub>ra</sub>   | 6.7  | 9.5         | 12.4 | μA   |
| Angle of half sensitivity   |  | φ                 |      | ± 60        |      | deg  |
| Wavelength of peak sensitivity  |  | λρ                |      | 900         |      | nm   |
| Range of spectral bandwidth   |  | λ <sub>0.1</sub>  |      | 430 to 1100 |      | nm   |
| Rise time   | $V_R$ = 10 V, $R_L$ = 1 k $\Omega$ , $\lambda$ = 820 nm                      | t <sub>r</sub>    |      | 100         |      | ns   |
| Fall time   | $V_R$ = 10 V, $R_L$ = 1 k $\Omega$ , $\lambda$ = 820 nm                      | t <sub>f</sub>    |      | 100         |      | ns   |

### BASIC CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)

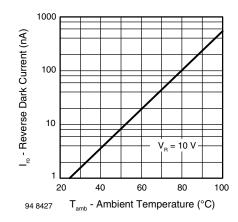


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

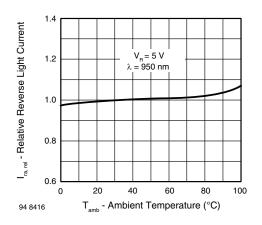


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

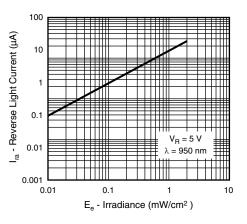
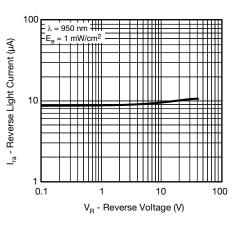


Fig. 3 - Reverse Light Current vs. Irradiance





2

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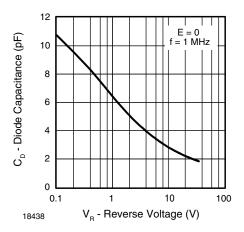


Fig. 5 - Diode Capacitance vs. Reverse Voltage

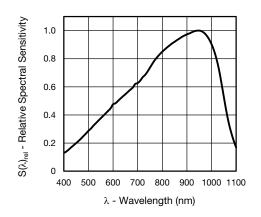


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

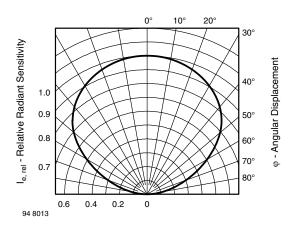


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

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### **REFLOW SOLDER PROFILE**

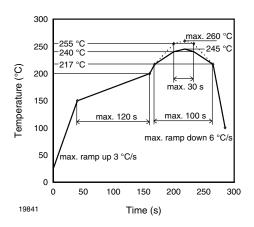


Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020

#### DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

### FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 72 h

Conditions: T<sub>amb</sub> < 30 °C, RH < 60 %

Moisture sensitivity level 4, acc. to J-STD-020.

#### DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

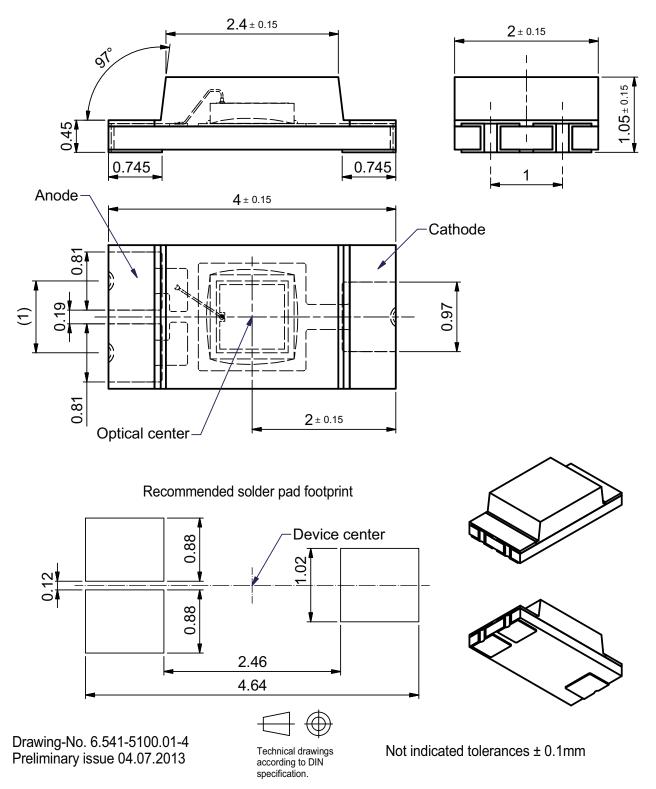
3



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### **PACKAGE DIMENSIONS** in millimeters

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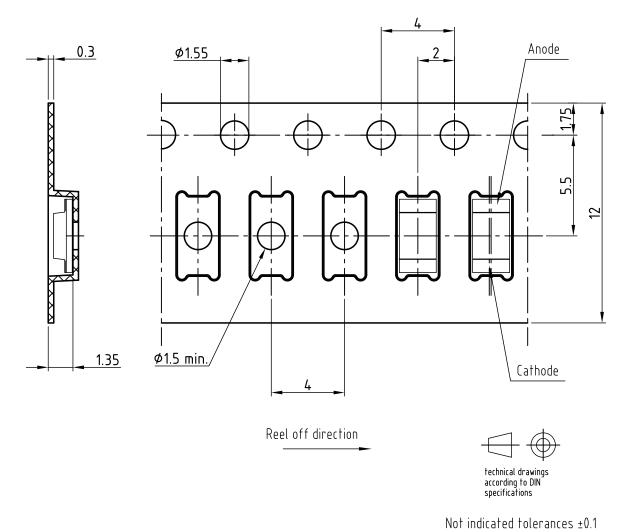
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#### **BLISTER TAPE DIMENSIONS** in millimeters

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Drawing refers to following Types: TEMD6010FX01 VEMD6x10X01 Drawing-No.: 9.700-5329.02-4 VEMD6x15X01 Prel Issue: 16.07.2013 All dimensions in mm

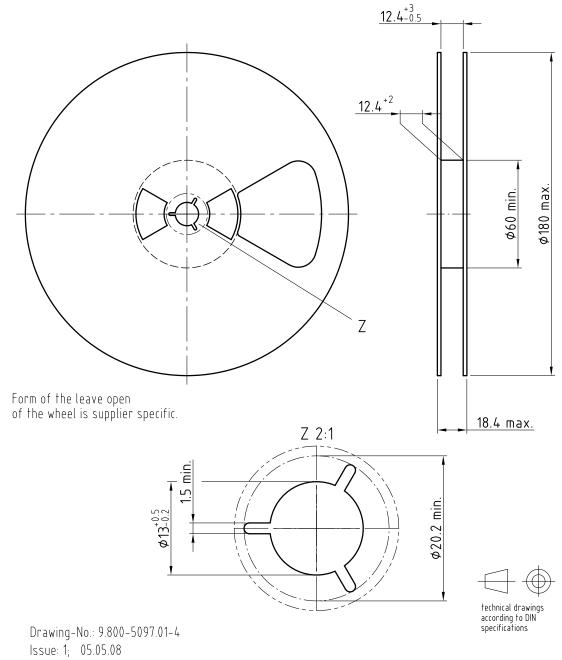
5



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#### **REEL DIMENSIONS** in millimeters



20874

6



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